

PLL Frequency Synthesizer for Electronic Tuning in Car Audio Systems



Overview

The LC72147V is a PLL frequency synthesizer for car audio systems. It can implement high-performance multifunction tuners and features a crystal oscillator circuit that supports AM up-conversion, a fast locking circuit, an A/D converter, and an LA1783/1750 IF counter buffer control pin.

Functions

- · High-speed programmable divider
 - FMIN: 10 to 180 MHz: Pulse swallower type
- IF counter
 - HCTR: 0.4 to 25 MHz: Frequency measurement
- Crystal oscillator: One of the following 4 frequencies may be selected: 10.35, 10.25, 7.2, and 4.5 MHz
 Reference frequency
 - One of 12 frequencies may be selected (when a 7.2 or 4.5 MHz crystal is used)

 $100^{\circ 1}$, 50, $30^{\circ 2}$, 25, 12.5, 6.25, 3.125, 10, $9^{\circ 2}$, 5, $3^{\circ 2}$, 1 kHz

Notes: 1. Cannot be used when a 10.35 or 10.25 MHz crystal is used

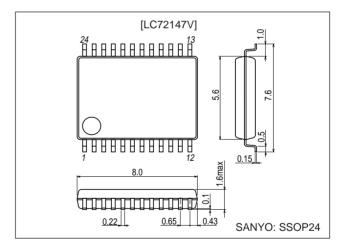
- 2. Cannot be used when a 10.25 MHz crystal is used
- Phase comparator
 - Supports dead band control
 - Built-in unlock detection circuit
 - Sub-charge pump for fast locking
 - Built-in deadlock clearing circuit
- Built-in MOS transistor for forming an active low-pass filter

- I/O ports General-purpose I/O: 5 pins
 - Output: n-channel: 3 pins, CMOS: 2 pins
 - IFBC pin (LA1783/1750 IF counter buffer control pin)
- · Serial data I/O
 - Supports communication with the controller in the CCB format.
- · Operating ranges
 - Supply voltage (V_{DD}): 4.5 to 6.5 V
 - Built-in regulator voltage (Vreg): 3.0 V (±10%)
 - Operating temperature: –40 to +85°C
- Package
 - SSOP-24

Package Dimensions

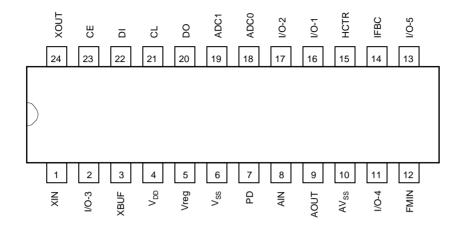
unit: mm

3175A-SSOP24

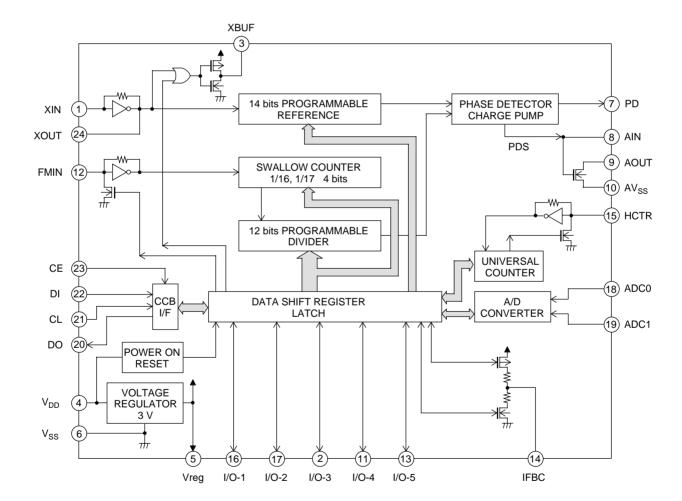


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Pin Assignment



Block Diagram



Specifications

Absolute Maximum Ratings at $Ta = 25^{\circ}C$, $V_{SS} = 0$ V

Parameter	Symbol	Pin	Conditions	Ratings	Unit
Supply voltage	V _{DD} max	V _{DD}		-0.3 to +7.0	V
	V _{IN} 1 max	CE, CL, DI, AIN		-0.3 to +7.0	
Maximum input voltage	V _{IN} 2 max	XIN, FMIN, HCTR, I/O-4, I/O-5, ADC0, ADC1		-0.3 to Vreg + 0.3	V
	V _{IN} 3 max	I/O-1 to I/O-3		-0.3 to +15	
	V _O 1 max	DO		-0.3 to +7.0	
Maximum output voltage	V _O 2 max	XOUT, IFBC, I/O-4, I/O-5, PD, XBUF		-0.3 to Vreg + 0.3	V
	V _O 3 max	I/O-1 to I/O-3, AOUT		-0.3 to +15	
	I _O 1 max	IFBC		0 to 1.0	
	I _O 2 max	I/O-4, I/O-5, XBUF		0 to 3.0	
Maximum output current	I _O 3 max	DO		0 to 6.0	mA
	I _O 4 max	I/O-1 to I/O-3		0 to 10	
	I _O 5 max	AOUT		0 to 35	
Allowable power dissipation	Pd max		Ta ≤ 85°C	150	mW
Operating temperature	Topr			-40 to +85	°C
Storage temperature	Tstg			-55 to +125	°C

Note: Power supply V_{DD} - V_{SS} , V_{reg} - V_{SS} : Capacitors of at least 2000 pF must be inserted between these pins when this device is used.

Allowable Operating Ranges at Ta = -40 to $85^{\circ}C$, $V_{SS} = 0$ V

D	0 1 1	D:	0 100		Ratings		11.7	
Parameter	Symbol	Pin	Conditions	min	typ	max	Unit	
Committee	V _{DD} 1	V_{DD}		4.5		6.5	V	
Supply voltage	V _{DD} 2	V_{DD}	Serial data retention voltage	2.5] V	
Regulator output voltage	Vreg	Vreg	4.5 ≤ V _{DD} ≤ 6.5 V	2.7	3.0	3.3	V	
High-level input voltage	V _{IH} 1	CE, CL, DI, I/O-1 to I/O-3		2.2		6.5	V	
	V _{IH} 2	I/O-4, I/O-5		2.2		Vreg		
Low-level input voltage	V _{IL}	CE, CL, DI, I/O-1 to I/O-5		0		0.8	V	
Output voltage	V _O 1	DO		0		6.5	V	
Output voltage	V _O 2	I/O-1 to I/O-3		0		13	\ \ \	
	f _{IN} 1	XIN	Sine wave, capacitance coupled	1.0		8.0		
Input frequency	f _{IN} 2	FMIN	Sine wave, capacitance coupled	10		180	MHz	
	f _{IN} 3	HCTR	Sine wave, capacitance coupled	0.4		25		
Guaranteed crystal oscillator	X'tal1	XIN, XOUT	*1	4.0		7.0	MHz	
frequency ranges	X'tal2	XIN, XOUT	*1	7.1		10.5	IVITZ	
	V _{IN} 1	XIN		200		900		
	V _{IN} 2-1	FMIN	10 ≤ f < 130 MHz *2	40		900		
Input amplitude	V _{IN} 2-2	FMIN	130 ≤ f ≤ 180 MHz *2	70		900	mVrms	
	V _{IN} 3-1	HCTR	0.4 ≤ f ≤ 25 MHz *3	70		900		
	V _{IN} 3-2	HCTR	8 ≤ f ≤ 12 MHz *4	100		900		
Input voltage range	V _{IN} 4	ADC0, ADC1		0		Vreg	V	
Data setup time	t _{SU}	DI, CL	*5	0.45			μs	
Data hold time	t _{HD}	DI, CL	*5	0.45			μs	
Clock low-level period	t _{CL}	CL	*5	0.45			μs	
Clock high-level period	t _{CH}	CL	*5	0.45			μs	
CE wait time	t _{EL}	CE, CL	*5	0.45			μs	
CE setup time	t _{ES}	CE, CL	*5	0.45			μs	
CE hold time	t _{EH}	CE, CL	*5	0.45			μs	
Data latch change time	t _{LC}		*5			0.45	μs	
Data autaut tima	t _{DC}	DO, CL	Depends on the value of the pull-up			0.2		
Data output time	t _{DH}	DO, CE	resistor used.			0.2	μs	

Notes:1. Recommended crystal oscillator CI values

CI \leq 120 Ω (Crystal: 4.5 MHz), CI \leq 70 Ω (Crystal: 7.2, 10.25, or 10.35 MHz)

Note that the crystal oscillator circuit characteristics depend on the printed circuit board and the particular components used. We recommend consulting the manufacturer of the crystal when designing this circuit.

- 2. Refer to the description of the structure of the programmable divider.
- 3. Serial data: CTC = 0
- 4. Serial data: CTC = 1
- 5. See the timing chart for serial data transfers.

Electrical Characteristics in the Allowable Operating Ranges

Parameter	Symbol	Pin	Conditions		Ratings		Unit	
	,			min	typ	max		
	Rf1	XIN			1.0		ΜΩ	
Internal feedback resistance	Rf2	FMIN			500		kΩ	
	Rf3	HCTR			250			
Hysteresis	V _{HIS}	CE, CL, DI			0.1 Vreg		V	
	V _{OH} 1	I/O-4, I/O-5	$I_{O} = -0.5 \text{ mA}$	Vreg – 0.5				
	- 011	, , , , , , , , , , , , , , , , , , , ,	$I_O = -1 \text{ mA}$	Vreg – 1.0			V	
High-level output voltage	V _{OH} 2	PD, AIN	$I_O = -1 \text{ mA}$	Vreg – 0.5				
3		·	$I_O = -2 \text{ mA}$	Vreg – 1.0				
	V _{OH} 3	XBUF	$I_{O} = -0.5 \text{ mA}$	Vreg – 0.5			V	
	V _{OH} 4	IFBC	$I_{O} = -0.1 \text{ mA}$	Vreg – 0.5			V	
	V _{OL} 1	I/O-4, I/O-5	$I_{O} = 0.5 \text{ mA}$			0.5	V	
	- 0L	, , , , , , , , , , , , , , , , , , , ,	I _O = 1 mA			1.0	·	
	V _{OL} 2	PD, AIN	I _O = 1 mA			0.5	V	
		·	I _O = 2 mA			1.0	-	
	V _{OL} 3	XBUF	I _O = 0.5 mA			0.5	V	
Low-level output voltage	V _{OL} 4	IFBC	I _O = 0.1 mA			0.5	V	
			I _O = 1 mA			0.2		
	V _{OL} 5	I/O-1 to I/O-3	I _O = 2.5 mA			0.5	V	
	· OLO	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	I _O = 5 mA			1.0	V	
			I _O = 9 mA			1.8		
	V _{OL} 6	DO	I _O = 5 mA			1.0	V	
	V _{OL} 7	AOUT	I _O = 30 mA, AIN = 2.0 V			1.5	V	
Mid-level output voltage	V _{OM}	IFBC	I _O = 20 μA	1.2	1.5	1.8	V	
	I _{IH} 1	CE, CL, DI	V _I = 6.5 V			5.0		
	I _{IH} 2	I/O-1 to I/O-3	V _I = 13 V			5.0		
High level input ourrent	I _{IH} 3	I/O-4, I/O-5, ADC0, ADC1, HCTR	V _I = Vreg			5.0	μA	
High-level input current	I _{IH} 4	XIN	V _I = Vreg	1.3		7		
	I _{IH} 5	FMIN	V _I = Vreg	2.5		14		
	I _{IH} 6	HCTR	V _I = Vreg	5.0		28		
	I _{IH} 7	AIN	V _I = Vreg			200	nA	
	I _{IL} 1	CE, CL, DI	V _I = 0 V			5.0		
	I _{IL} 2	I/O-1 to I/O-3	V _I = 0 V			5.0		
Low lovelines to surrent	I _{IL} 3	I/O-4, I/O-5, ADC0, ADC1, HCTR	V _I = 0 V			5.0	μA	
Low-level input current	I _{IL} 4	XIN	V _I = 0 V	1.3		7		
	I _{IL} 5	FMIN	V _I = 0 V	2.5		14		
	I _{IL} 6	HCTR	V _I = 0 V	5.0		28		
	I _{IL} 7	AIN	V _I = 0 V			200	nA	
Output off lookogs surrent	I _{OFF} 1	I/O-1 to I/O-3	V _O = 13 V			5.0	,	
Output off leakage current	I _{OFF} 2	DO	V _O = 6.5 V			5.0	μA	
High-level 3-state off leakage current	I _{OFFH}	PD	V _O = Vreg		0.01	200	nA	
Low-level 3-state off leakage current	I _{OFFL}	PD	V _O = 0 V		0.01	200	nA	
Input capacitance	C _{IN}	FMIN			6		PF	
A/D converter linearity error	Err	ADC0, ADC1		-1/2		1/2	LSB	
Pull-down transistor on resistance	Rpd	FMIN		80	200	600	kΩ	
Supply current	I _{DD}	V _{DD}	X'tal = 10.35 MHz $f_{IN}2 = 180 \text{ MHz}$ $V_{IN}2 - 2 = 70 \text{ mVrms}$ $f_{IN}3 = 25 \text{ MHz}$ $V_{IN}3 - 1 = 70 \text{ mVrms}$		12		mA	

Pin Functions

Pin No.	Symbol	Usage	Function	Pin circuit
1 24	XIN XOUT	X'tal OSC	Crystal oscillator connection. (4.5, 7.2, 10.25, or 10.35 MHz)	
12	FMIN	Local oscillator signal input	 FMIN is selected by setting DVS in the control data to 1. Input frequency: 10 to 180 MHz The signal is transmitted to the swallow counter. The divisor can be set to a value in the range 272 to 65,535. 	
23	CE	Chip enable	This pin must be set to the high level when inputting serial data to the LC72147V DI pin and when outputting serial data from the DO pin.	<u> </u>
21	CL	Clock	Data synchronization clock signal used when inputting serial data to the LC72147V DI pin and when outputting serial data from the DO pin.	<u> </u>
22	DI	Input data	Serial data input for transferring data from the controller to the LC72147V.	s>
20	DO	Output data	Serial data output for transferring data from the LC72147V to the controller.	7
4	V _{DD}	Power	LC72147V power supply. A voltage in the range 4.5 to 6.5 V must be provided when the PLL circuit is operating. The power-on reset circuit operates when power is first applied.	
5	Vreg	Regulator output	Regulator output. A capacitor must be inserted between Vreg and Vss. The output voltage (3.0 V ±10%) is supplied to internal circuits.	
6	V _{SS}	Ground	• LC72147V ground.	
14	IFBC	IF buffer control	 The LC72147V can control the LA1783/1750 IF buffer output. This is a 3-state output. (0 V, Vreg/2 = 1.5 V, and Vreg = 3 V) 	
16 17 2	I/O-1 I/O-2 I/O-3	General-purpose I/O ports	 General-purpose I/O ports. The outputs are open-drain circuits. After the power-on reset, I/O-1 and I/O-2 function as input ports. I/O-3 functions as an output port fixed at the low level. The input/output state of these ports can be set using the I/O-1 to I/O-3 bits in the serial data sent from the controller. 	

Continued from preceding page.

Pin No.	Symbol	Usage	Function	Pin circuit
11 13	I/O-4 I/O-5	General-purpose I/O ports	 General-purpose I/O ports. The outputs are complementary output circuits. After the power-on reset, these ports function as input ports. The input/output state of these ports can be set using the I/O-4 and I/O-5 bits in the serial data sent from the controller. 	
18 19	ADC0 ADC1	A/D converter input	A/D converter input The A/D converter is a 6-bit successive-approximation circuit. See the item on the structure of the A/D converter for details.	
7	PD	Charge pump output	PLL charge pump output When the frequency created by dividing the local oscillator signal frequency by N is higher than the reference frequency, a high level is output from the PD pin. When lower, a low level is output. The PD pin goes to the high-impedance state when the frequencies match.	
15	HCTR	General-purpose counter	HCTR is selected by setting CTS in the control data to 1. Input frequency: 0.4 to 25 MHz The signal is input to a divide-by-2 circuit and the result is input to a general-purpose counter. This counter can also be used as an integrating counter. The counter value is output as the result of the count, MSB first, from the DO pin. See the item describing the structure of the general-purpose counter for details.	
3	XBUF	Crystal oscillator buffer	Output buffer for the crystal oscillator circuit When XB in the serial data is set to 1, the output buffer operates and the crystal oscillator signal (a pulse signal) is output. When XB is 0, XBUF outputs a low level. (After the power-on reset, XB is set to 0 and the output buffer is fixed at the low level.)	XOUT THE TOTAL T

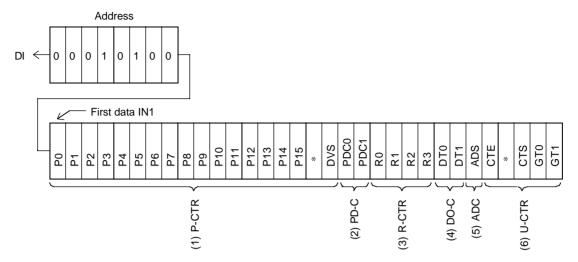
Serial Data I/O Methods

Data is input to and output from the LC72147V using the Sanyo CCB (Computer Control Bus) format, which is the serial bus format used by Sanyo audio ICs. This IC adopts a CCB format with an 8-bit address.

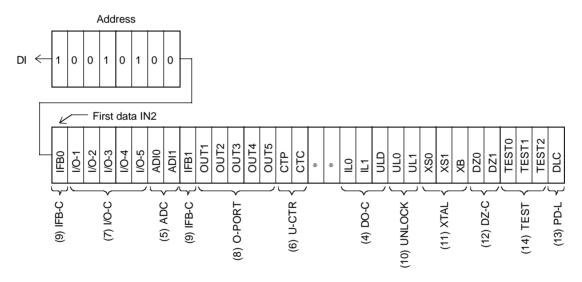
	1/0 1-				Addr	ess				Content		
	I/O mode	В0	B1	B2	ВЗ	A0	A1	A2	АЗ	Content		
										Control data input (serial input) mode.		
[1]	IN1 (82)	0	0	0	1	0	0	1	0	• 32 bits of data are input.		
	(52)							-		 See the "DI Control Data (Serial Data Input) Structure" item for details on the content of the input data. 		
										Control data input (serial input) mode.		
[2]	IN2 (92)	1	0	0	1	0	0	1	0	32 bits of data are input.		
	, ,									• See the "DI Control Data (Serial Data Input) Structure" item for details on the content of the input data.		
										Data output (serial data output) mode.		
[3]	OUT (A2)	0	1	0	1	0	0	1	0	The number of bits output is equal to the number of clock cycles.		
	, ,									See the "DO Output Data (Serial Data Output) Structure" item for details on the content of the output data.		
	CE	BC		B1		B2	1			I/O mode determined		

DI control data (serial data input) structure

(1) IN1



(2) IN2



*: Don't care

DI control data description

No.	Control block/data					Content		Related data	
		This data :	This data sets the divisor for the programmable divider						
		P0 is the L	SB, and	P15 is th	ne MSB o	f this binary value.			
	Programmable divider data	DVS = 0:	The FMIN	N pin is p	ulled dow	n.			
(1)	P0 to P15	1: \$	1: Selects the FMIN pin.						
	DVS	Div	isor setti	ng (N): 2	72 to 65,	536			
		Inp	Input frequency range: 10 to 180 MHz						
		*: See the "F	rogramr	mable Div	vider Stru	cture" item for details.			
		This data	controls t	he sub-c	harge pu	mp.			
		PDC1	PDC	0	Sub-	charge pump state	(* : don't care)		
		0	*	High	n impeda				
		1	0			o operating (PLL unlocked)			
(2)	Sub-charge pump control data	1	1	_	· ·	o operating (normal operation)		UL0, UL1, DLC	
	PDC0, PDC1					·	I		
		1	• .			nected internally to the gate of that harge pump can be used in con			
						a high-speed locking circuit.	ijunction with the FD		
		See the "C	harge P	ump Stru	cture" ite	m for details.			
		Reference				D-f	(1-1 1-)		
		R3 0	R2 0	R1 0	R0 0	Reference frequence	cy (KHZ)		
		0	0	0	1	50			
		0	0	1	0	25			
		0	0	1	1	25			
		0	1	0	0	12.5			
		0	1	0	1	6.25			
		0	1	1	0	3.125			
		0	1	1	1	3.125			
		1	0	0	0	10			
(3)	Reference divider data	1	0	0	1	9 *2			
(-)	R0 to R3	1	0	1	0	5			
		1	0	1	1	1			
		1	1	0	0	3 *2			
		1	1	0	1	30 *2			
		1	1	1	0	*3 PLL inhibit + X'tal OSC stop	p		
		1	1	1	1	*3 PLL inhibit			
		2. Illeg 3. PLI The progra	gal value _ inhibit (ammable	when a obackup not divider I	crystal os node) block is s	cillator frequency of 10.25 or 10 cillator frequency of 10.25 MHz stopped, the FMIN pin is pulled floating state.	is selected.		

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No.	Control block/data	Content	Related data					
		Data that determines the output of the DO and I/O-5 pins						
		ULD DT1 DT0 DO pin I/O-5 pin						
		0 0 Low when unlocked						
		0 0 1 end-AD OUT5 *2						
		0 1 0 end-UC						
		0 1 1 IN *1						
		1 0 0 Open						
		1 0 1 end-AD Low when unlocked *2						
		1 1 0 end-UC						
		1 1 1 IN*1						
		end-AD: A/D converter operation completion						
		end-UC: General-purpose counter operation completion						
	DO, I/O-5 pin control data		OUT5					
(4)	ULD	DO	I/O-1					
, ,	DT0, DT1	\ \tag{\tag{\tag{\tag{\tag{\tag{\tag{	I/O-2					
	ILO, IL1	Start Completion (I-1 change) CE : Hi	I/O-5					
		Note: 1.						
		IL1 IL0 IN						
		0 0 Open						
		0 1 I-1 (pin state)						
		1 0 I-2 (pin state)						
		1 1 DO goes low when I-1 changes. *						
		However, if I/O-1 and I/O-2 are set to output mode, they go to the open state.						
		Note: 2. Invalid if the I/O-5 pin is set to input mode.						
		Caution: Cannot be used in crystal oscillator stop mode (The DO pin will not change state.)						
		[When the reference divider data is R3 = R2 = R1 = 1, and R0 = 0.]	-					
		A/D converter conversion start data						
		ADS = 1: Resets and starts the A/D converter						
		ADS = 0: Resets the A/D converter						
	A/D converter control data	ADI1 ADI0 A/D converter input pin						
	ADS	1 1 Stopped						
(5)	ADIO	1 0 ADC0						
	ADI1	0 1 ADC1						
	אטוו	0 0 ADC0, ADC1						
		If both the ADC0 and ADC1 pins are specified as A/D converter inputs, the levels are converted sequentially in the order ADC0 first and the ADC1. See the "A/D Converte Structure" item for details.						

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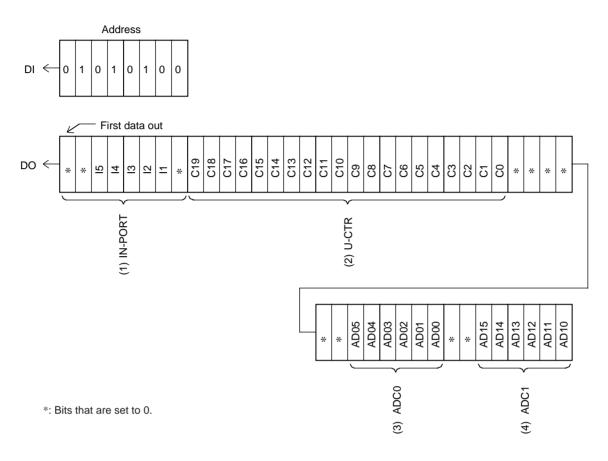
No.	Control block/data	Content						
			Selects the general-purpose counter input pin (HCTR). CTS = 1: Selects the HSTR pin. CTS = 0: Pulls down the HCTR pin. General-purpose counter measurement start data CTE = 1: Starts the counter. CTE = 0: Resets the counter. Determines the measurement time (frequency mode) and number of periods (period mode).					
	General-purpose counter control data CTS, CTE	GT1	GT0	Frequency m Measurement time	Wait	time	Period measurement mode	
(6)	GT0, GT1			Wodediement amo	CTP = 0	CTP = 1	mode	
	СТР	0	0	4 ms	3 to 4 ms		One period	
	СТС	0	1	8	3 to 4 ms		One period	
		1	1	32 64	7 to 8 ms	1 to 2 ms	Two periods Two periods	
		CTP = 0: When the counter has been reset (CTE = 0), pulls down the general-purpose counter input. CTP = 1: When the counter has been reset (CTE = 0), does not pull down the general-purpose counter input, and shortens the wait time. However, immediately after CTP is set to 1, the counter start must be delayed until the general-purpose counter input pin has been biased. The input sensitivity is reduced when CTC is set to 1. (Sensitivity: 10 to 30 mV rms)						
(7)	I/O port control data IO-1 to I/O-5	[Data] :	= 0: Inpo 1: Out	put port r-on reset, the I/O-1, I/			are set up as input ports. I/O-3	OUT1 to OUT5 ULD
(8)	Output port data OUT1 to OUT5	[Data] :	Data that determines the output from output ports O-1 to O-5. [Data] = 1: Open or high level. 0: Low *: Invalid when the corresponding port is set up as an input port or as the unlock state indicator output.					
(9)	IFBC port control data IFB0, IFB1	1FB0 0 0 1 1	IFB1 0 1 0 1 PLL inh	•	5 V) 5 V) 5 V) or stop moo		R1 = R2 = R3 = 1), the IFBC level after the power-on reset.	

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No.	Control block/data	Content					
		Width selection for the phase error (ØE) detection function used to determine the PLL locked/unlocked state. When a phase error greater than the ØE detection width from the table occurs, the PLL circuit is seen as in the unlocked state. When unlocked, the detection pin (DO or I/O-5) goes to the low state.					
		UL1 UL0 øE detection width Detection pin output					
		0 0 Stopped Open					
		0 1 0 øE is output directly					
	Unlock state detection data	1 0 ±0.5 μs ØE is extended by 1 to 2 ms.	ULD				
(10)	ULO, UL1	1 1 ±1 µs ØE is extended by 1 to 2 ms.	DT0, DT1				
		ØE D0 VO5 1 to 2 ms Unlocked state output					
		Crystal oscillator selection data					
		XS1 XS0 X'tal OSC					
		0 0 4.5 MHz					
		0 1 7.2 MHz					
	Crystal oscillator circuit	1 0 10.25 MHz					
(11)	XS0, XS1	1 1 10.35 MHz	R0 to R3				
	ХВ	*: After the power-on reset, 10.25 MHz is selected. • Crystal oscillator buffer (XBUF) output control data XB = 0: Buffer output is turned off. (This mode is selected after the power-on reset.) XB = 1: Buffer output is turned on.					
		Controls the phase comparator dead band.					
		DZ1 DZ0 Dead band mode					
		0 0 DZA					
(12)	Phase comparator control data	0 1 DZB					
, ,	DZ0, DZ1	1 0 DZC					
		1 1 DZD					
		*: The phase comparator operates in DZA mode after the power-on reset.					
		Bit that forcible sets the charge pump output to the low level.					
		DLC = 1: Low level					
(13)	Charge pump control data	DLC = 0: Normal operation					
, ,	DLC	*: If a deadlock occurs due to the VCO control voltage (Vtune) going to zero and stopping the VCO oscillator, set the charge pump output to the low level and set Vtune to V _{CC} to escape from the deadlocked state. Normal operation is selected after the power-on reset.					
		IC test control data					
	IC test data	These bits must be set as follows during normal operation.					
(14)	TEST0	TEST0 = 0					
()	TEST1	TEST1 = 0					
	TEST2	TEST2 = 0					
		*: After the power-on reset, the test data is all set to zero.					

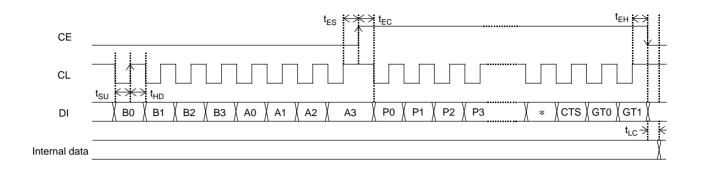
Structure of the DO Output Data (serial output data)

(3) OUT

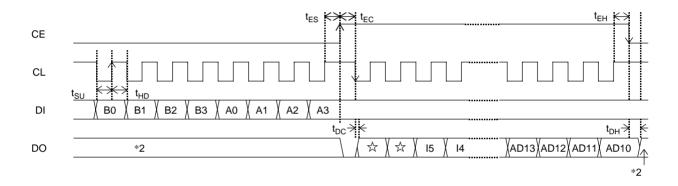


No.	Control block/data	Content	Related data
(1)	I/O port data I5 to I1	The bits I1 to I5 are set to the latched states of the I/O pins I/O-1 to I/O-5. These states are latched at the point the IC enters data output mode. The pin states are latched regardless of the pin mode (input or output). Pin state = high: 1 low: 0	I/O-1 to I/O-5
(2)	General-purpose counter binary data C19 to C0	The bits C19 to C0 are set to the latched content of the 20-bit binary general-purpose counter. C19 ← MSB of the binary counter C0 ← LSB of the binary counter	CTS0 CTS1 CTE
(3)	A/D converter ADC0 data AD05 to AD00	The bits AD05 to AD00 are set to the latched result of the A/D conversion of the ADC0 pin input signal. AD05 ← MSB AD00 ← LSB	ADIO ADI1 ADS
(4)	A/D converter ADC1 data AD15 to AD10	The bits AD15 to AD10 are set to the latched result of the A/D conversion of the ADC1 pin input signal. AD15 ← MSB AD10 ← LSB	ADIO ADI1 ADS

Serial data input (IN1/IN2) $~t_{SU},\,t_{HD},\,t_{ES},\,t_{EC},\,t_{EH},>0.45~\mu s~t_{LC}<0.45~\mu s$



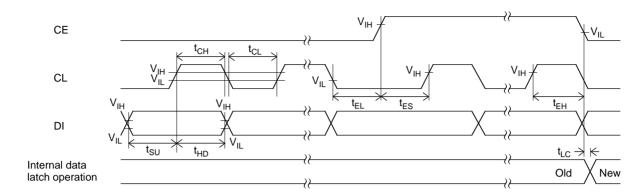
Serial data output (OUT) $t_{SU},\,t_{HD},\,t_{ES},\,t_{EC}>0.45~\mu s$ $t_{DC},\,t_{DH}<0.2~\mu s$ *1



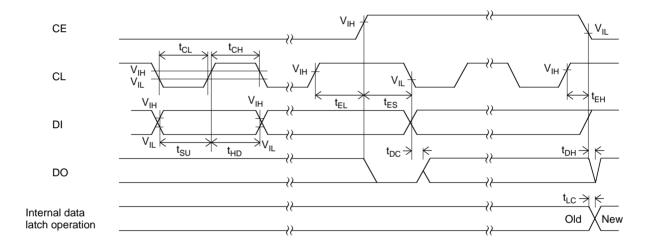
Notes: 1. The DO pin is an n-channel open drain output, and thus the data switching time will differ depending on the value of the pull-up resistor used and the printed circuit board capacitance.

2. The DO pin is normally open.

Serial data timing

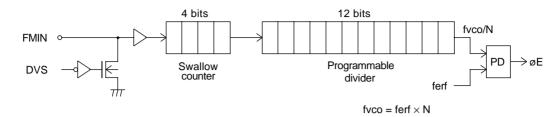


<When CL is stopped at the low level>



<When CL is stopped at the high level>

Programmable divider structure

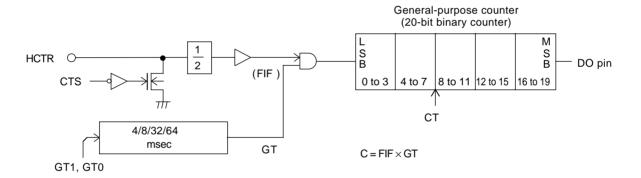


DVS	Set divisor (N)	Input frequency Minimum inp	FMIN	
1	4 070 +- 05505	10 ≤ f < 130	130 ≤ f ≤ 180	Selected
'	272 to 65535	40 mVrms	70 mVrms	Selected
0	_	_	_	Pulled down

General-purpose counter structure

The LC72147V's general-purpose counter is a 20-bit binary counter.

The result of the count operation can be read out MSB first from the DO pin.



The measurement time when the general-purpose counter is used for frequency measurement is set to either 4, 8, 32, or 64 ms by the GT0 and GT1 bits. The frequency of the input to the HCTR pin can be measured by determining how many pulses were input to the general-purpose counter during this measurement time.

Check signal frequency

X'tal OSC	4.5 MHz	7.2 MHz	10.25 MHz	10.35 MHz	
X tai OSC				fref = 30, 9, 3 kHz	fref: other than 30, 9, 3 kHz
Check signal	900 kHz	900 kHz	1025 kHz	1030 kHz	1150 kHz

The CTC data switches the input sensitivity. The input sensitivity is reduced when CTC is set to 1.

CTC	HCTR: Minimum input sensitivity rating			
CIC	0.4 ≤ f < 8	8 ≤ f < 12	12 ≤ f < 25	
0 (Normal mode)	70 mVrms	70 mVrms (10 to 20 mVrms)	70 mVrms	
1 (Reduced sensitivity mode)	_	100 mVrms (30 to 40 mVrms)	_	

^{-:} No sensitivity rating (not guaranteed)

^{():} Rated value (reference value)

CTP data: Determines the state of the general-purpose counter input pin (HCTR) when the general-purpose counter is reset (CTE = 0).

CTP = 0: The general-purpose counter input pin is pulled down.

1: The general-purpose counter input pin is not pulled down, and the wait time is shortened by 1 to 2 ms.

IF CTP is to be set to 1, set CTP to 1 at least 4 ms before the counter is started by setting CTE to 1.

Leave CTP set to 0 if the counter will not be used.

	GT0	Frequency measurement mode			
GT1		Measurement time	Wait time		
		Measurement time	CTP = 0	CTP = 1	
0	0	4 ms	3 to 4 ms	1 to 2 ms	
0	1	8 ms	3 10 4 1115		
1	0	32 ms	7 to 8 ms		
1	1	64 ms	7 10 0 1115		

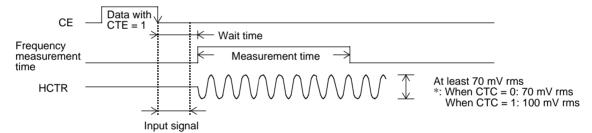
IF counter operation

Reset the general-purpose counter in advance by setting CTE to 0 before starting the counter.

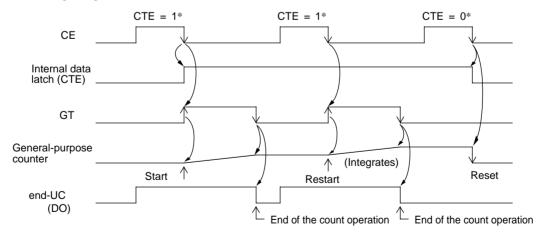
A general-purpose counter count operation is started by setting the CTE bit in the serial data to 1. The serial data takes effect internally to the LC72147V when the CE pin input level is changed from high to low. The input to the HCTR pin must be provided before the wait time has elapsed after CE was set low.

Next, the result of the general-purpose counter count after the measurement completes must be read out while CTE is still set to 1. This is because the general-purpose counter is reset when CTE is set to 0.

Note that the signal input to the HCTR pin is first divided by 2 internally to the IC and then input to the general-purpose counter. Therefore, the result of the general-purpose counter count is a value that corresponds to 1/2 of the frequency actually input to the HCTR pin.



When used as an integrating counter



*CTE: 0 → • Resets the general-purpose counter

1 → Starts the general-purpose counter

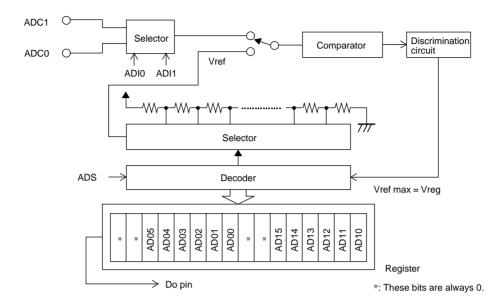
Restarts the counter if set to 1 again.

In integrating count mode, the count value of the general-purpose counter is accumulated. Care must be taken to handle counter overflow correctly. The count value will be in the range 0_H to FFFFF_H.

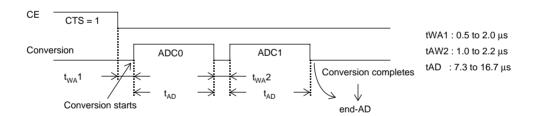
An integrating count operation is performed by sending the serial data (IN1) again with the CTE bit still set to 1. This restarts the general-purpose counter measurement operation and adds the new counts to the previous counter value.

A/D converter structure

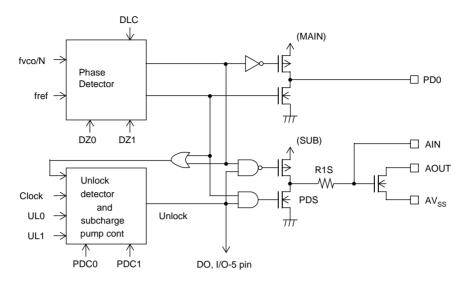
The LC72147V A/D converter is a 6-bit successive-approximation converter. It features a conversion time of about $17 \, \mu s$. The full-scale voltage level is the Vreg level, which corresponds to a data value of $3F_H$.



ADI1	ADI0	Input pin
1	1	Illegal setting
1	0	ADC0
0	1	ADC1
0	0	ADC0/ADC1



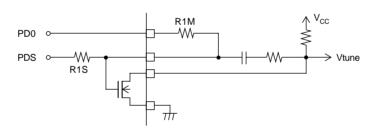
Charge pump structure



PDC1	PDC0	PDS (Sub-charge pump state)
0	*	High impedance
1	0	Charge pump operating (PLL unlocked)
1	1	Charge pump operating (normal operation)

DLC	PD1, PD0, PDS
0	Normal operation
1	Forcibly set to the low level

When the unlocked state is detected when the channel is changed, the PDS (sub-charge pump) operates, R1 goes to RIM/R1S (R1S = 100Ω), the low-pass filter time constant is reduced, and PLL locking is accelerated.



*: The unlock state detection bit UL1 must be set to 1. The unlock detection width is set to either ± 0.5 μ s or ± 1.0 μ s and when a phase difference larger than this is detected, the unlocked state is recognized and the sub-charge pump operates. When the state approaches the locked state and the phase difference becomes less than the amount set as the unlock detection width, the sub-charge pump stops operating and the pin goes to the high-impedance state.

Other items

(1) Notes on the phase detector dead band

	DZ1	DZ0	Dead band mode	Charge pump	Dead band
	0	0	DZA	ON/ON	−-0 s
Ī	0	1	DZB	ON/ON	−0 s
Ī	1	0	DZC	OFF/OFF	+0 s
	1	1	DZD	OFF/OFF	++0 s

When the charge pump operates in ON/ON mode, the charge pump generates correction pulses even when the PLL is locked. Here, it is easy for the loop to become unstable, and special care is required in designs that use this mode. The following problems may occur in ON/ON mode.

- Side bands may be generated due to reference frequency leakage.
- Side bands may be generated due low-frequency leakage due to the envelope of the correction pulses.

When a dead band is present (OFF/OFF mode), the loop will be stable, but it will be harder to acquire a good C/N ratio. On the other hand, with the mode that does not have a dead band (ON/ON mode), it will be easier to acquire a high C/N ratio, but harder to acquire loop stability.

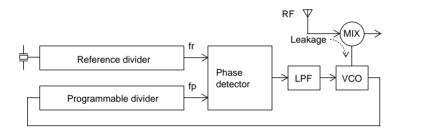
Therefore, the DZA and DZB modes, in which there is no dead band, can be effective if either a high signal-to-noise ratio of 90 to 100 dB in FM reception or an increased pilot margin in AM stereo reception is required.

Inversely, if such a high FM signal-to-noise ratio is not required for FM reception, or an adequate pilot margin can be acquired for AM stereo reception, then the DZC and DZD modes, in which a dead band is present, may be more effective.

Dead zone (dead band) definition

The phase comparator compares fp with the reference frequency (fr) as shown in figure 1. This circuit outputs a voltage V (A) that is proportional to the phase difference Ø as shown in figure 2. However, due to internal delays and other factors, the actual IC is unable to compare small phase differences, and thus a dead zone (B) appears in the output. To achieve a high signal-to-noise ratio in the end product, the dead zone should be as small as possible.

However, in popularly-priced models, there are cases where a somewhat wider dead zone may be easier to work with. This is because in some situations, such as when a powerful signal is applied to the RF input, in popularly-priced models there may be RF leakage from the mixer to the VCC. When the dead zone is narrow, outputs to correct this leakage are output, that output in turn modulates the VCO, and generates a beat signal with the RF.



(A) (B) Ø (nsec) Dead zone

Figure 1 Figure 2

(2) Notes on the FMIN and HCTR pins

The coupling capacitor must be located as close as possible to these pins. A capacitance of approximately 100 pF is desirable.

In particular, if the HCTR pin capacitor is over about 1000 pF, the time required to reach the bias level may become excessive, and incorrect counting may occur due to the relationship with the wait time.

(3) Notes on the IF counting \rightarrow SD must be used in conjunction with IF counting.

If the general-purpose counter is used to count the IF frequency, the application microcontroller must test the state of the IF IC SD (station detect) signal, and only if the SD signal is present, turn on the IF counter buffer output and perform an IF count operation. Methods in which auto-search operations are implemented only using the IF count may incorrectly stop at frequencies where no station is present due to leakage from the IF counter buffer.

(4) Using the DO pin

At times other than data output mode, the DO pin can also be used to check for general-purpose counter count operation completion, to output the unlock state detection signal, and to check for changes in the input pins.

Note that the states of the input pins (I/O-1 and I/O-2) can be directly input to the system microcontroller through the DO pin.

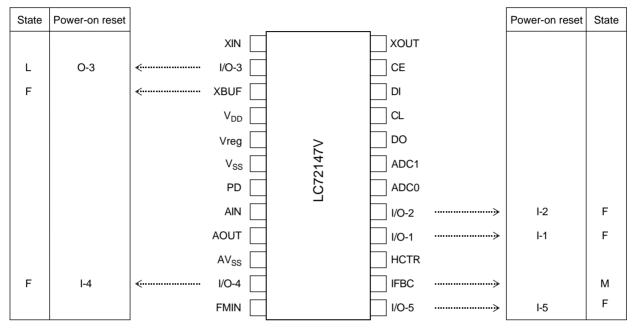
(5) Power supply pins

Capacitors of over 2000 pF must be inserted between the VDD and VSS power supply pins and between Vreg and VSS to reduce noise. These capacitors must be located as close to the VDD, Vreg, and VSS pins as possible.

(6) Notes on VCO design

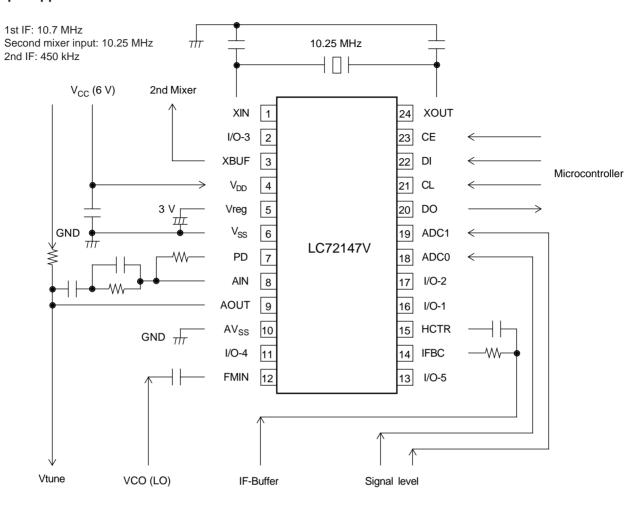
The VCO must be designed so that the VCO oscillation does not stop if the control voltage (Vtune) becomes 0 V. If it is possible for this oscillator to stop, use the charge pump control data (DLC) to forcible set Vtune to VCC temporarily to prevent the PLL circuit from deadlocking. (This function is called a deadlock clear circuit.)

Pin states during a power-on reset



F : Floating L : Low M : Medium

Sample Application Circuit



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